



Data Sheet

Customer :

Product : Small Signal Schottky Diode-Low VF

Part No.: B120LW/B130LW/B140LW

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1 Amperes Surface Mount Schottky Barrier Rectifiers

Voltage : 20 to 40Volts

Features

- Tiny plastic SMD package
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- Guardring for over voltage protection
- Ultra high-speed switching
- Silicon epitaxial planar chip, metal silicon junction
- Lead-free parts meet environmental standards of MIL-STD-19500/228
- Halogen free



Mechanical Data

Epoxy : UL94-V0 rated flame retardant

Case : Molded Plastic, SOD-123

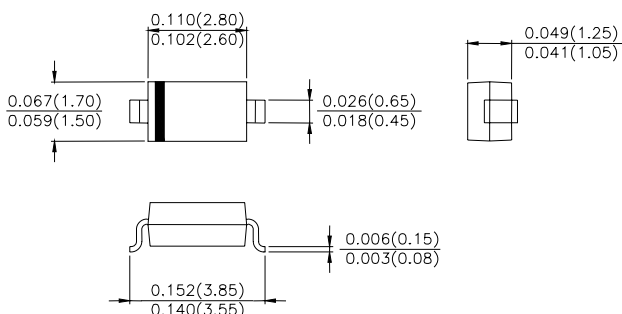
Terminals : Solder plated, Solderable per MIL-STD-750, Method 2026

Polarity : Indicated by cathode end

Weight : 0.0004 ounce, 0.010 gram

Packaging : 2.5Kpcs per 7" reel or 3Kpcs per 7" reel

Package Dimensions in inches(millimeters): SOD-123



Maximum Ratings And Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Parameter	Symbol	B120LW	B130LW	B140LW	Unit
Marking Code		B2	B3	B4	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	20	30	40	V
Maximum RMS Voltage	V_{RMS}	14	21	28	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	V
Maximum Instantaneous Forward Voltage@1.0A, $T_A=25^\circ\text{C}$	V_F	0.43		0.45	V
Operating Temperature	T_J	-50 ~ +100			°C

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward Rectified Current	See Fig.2	I_O			1.0	A
Forward Surge Current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I_{FSM}			5.5	A
Reverse Current	$V_R=V_{RRM}$, $T_A=25^\circ\text{C}$	I_R			1.0	mA
	$V_R=V_{RRM}$, $T_A=100^\circ\text{C}$				20	
Thermal Resistance	Junction to ambient	$R_{\theta JA}$		42		°C/W
Diode Junction Capacitance	f=1MHz and applied 4V DC reverse voltage	C_J		130		pF
Storage Temperature		T_{STG}	-50		+150	°C

■ Rated and Characteristic Curve

FIG.1-TYPICAL FORWARD CHARACTERISTICS

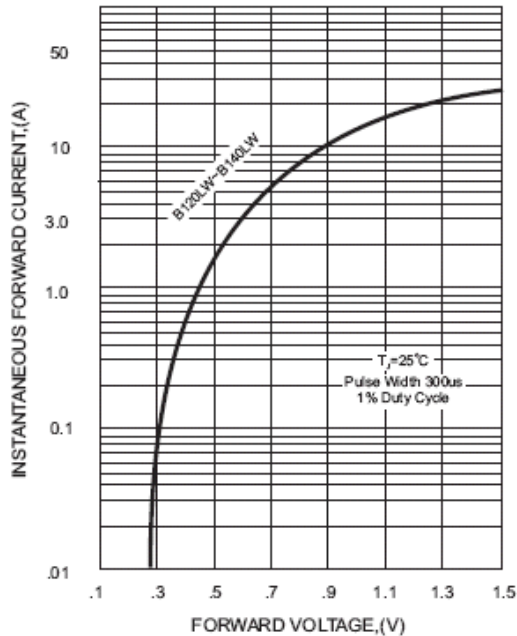


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

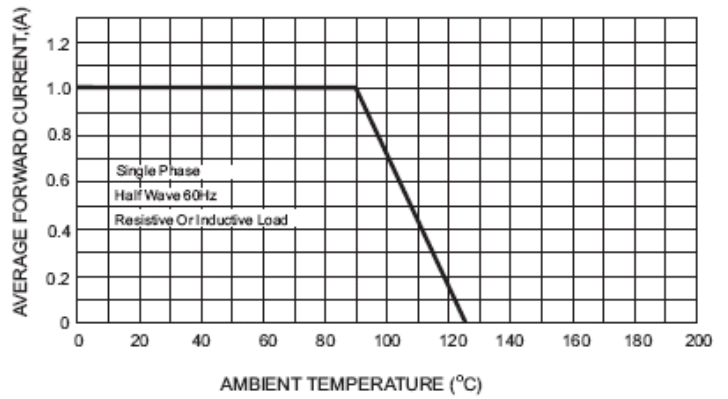


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

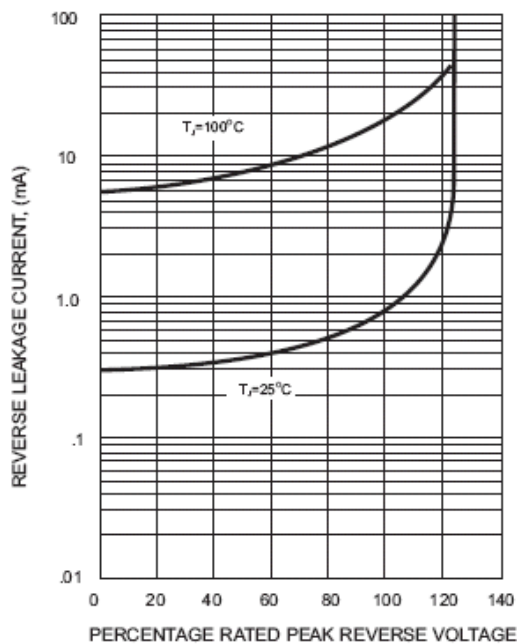


FIG.4-TYPICAL JUNCTION CAPACITANCE

